NSN 5961-00-405-0465

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View Online at https://aerobasegroup.com/nsn/5961-00-405-0465

Inclosure Material:

Metal

Overall Length:

Between 0.345 inches and 0.400 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

Between 0.423 inches and 0.438 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

100.0 breakdown voltage, collector-to-base, emitter open and 80.0 breakdown voltage, collector-to-emitter, base open and 6.0 breakdown voltage, emitter-to-base, collector open

Current Rating Per Characteristic:

Between 1.00 amperes source cutoff current and 5.00 amperes source cutoff current

Power Rating Per Characteristic:

2.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Junction pattern arrangement: pnp

Precious Material And Location:

Terminals and surfaces gold

Precious Material:

Gold

Test Data Document:

80063-sm-d-2019501 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

Thread Series Designator:

Unf

Terminal Type And Quantity:

1 threaded stud and 2 tab, solder lug

Shelf Life:

N/a

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Demilitarization:

No

Fiig:

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